

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Non-Repetitive Current Pulse Derated Above T _A = +25°C) (Note 5)	P _{PK}	1500	W
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load (Notes 5, 6, & 7)	I _{FSM}	200	A
Steady State Power Dissipation @ T _L = +75°C	PM(AV)	5.0	W
Instantaneous Forward Voltage @ I _{PP} = 100A (Notes 5 & 7)	V _F	3.5	V

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Operating Temperature Range	T _J	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +175	°C

Notes: 5. Valid provided that terminals are kept at ambient temperature.
6. Measured with 8.3ms single half sine-wave. Duty cycle = 4 pulses per minute maximum.
7. Unidirectional units only.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Part Number Add C For Bidirectional (Note 8)	Reverse Standoff Voltage	Breakdown Voltage V _{BR} @ I _T (Note 9)		Test Current	Max. Reverse Leakage @ V _{RWM} (Note 11)	Max. Clamping Voltage @ I _{pp} (Note 10)	Max. Peak Pulse Current	Marking Code	
	V _{RWM} (V)	Min (V)	Max (V)	I _T (mA)	I _R (μA)	V _C (V)	I _{PP} (A)	BI	UNI
SMCJ5.0(C)AQ	5.0	6.40	7.07	10	1000	9.2	163.0	BDE	GDE
SMCJ6.0(C)AQ	6.0	6.67	7.37	10	1000	10.3	145.6	BDG	GDG
SMCJ6.5(C)AQ	6.5	7.22	7.98	10	500	11.2	133.9	BDK	GDK
SMCJ7.0(C)AQ	7.0	7.78	8.60	10	200	12.0	125.0	BDM	GDM
SMCJ7.5(C)AQ	7.5	8.33	9.21	1.0	100	12.9	116.3	BDP	GDP
SMCJ8.0(C)AQ	8.0	8.89	9.83	1.0	50	13.6	110.3	BDR	GDR
SMCJ8.5(C)AQ	8.5	9.44	10.4	1.0	20	14.4	104.2	BDT	GDT
SMCJ9.0(C)AQ	9.0	10.00	11.1	1.0	10	15.4	97.4	BDV	GDV
SMCJ10(C)AQ	10.0	11.10	12.3	1.0	5.0	17.0	88.2	BDX	GDX
SMCJ11(C)AQ	11.0	12.20	13.5	1.0	5.0	18.2	82.4	BDZ	GDZ
SMCJ12(C)AQ	12.0	13.30	14.7	1.0	5.0	19.9	75.3	BEE	GEE
SMCJ13(C)AQ	13.0	14.40	15.9	1.0	5.0	21.5	69.7	BEG	GEG
SMCJ14(C)AQ	14.0	15.60	17.2	1.0	5.0	23.2	64.7	BEK	GEK
SMCJ15(C)AQ	15.0	16.70	18.5	1.0	5.0	24.4	61.5	BEM	GEM
SMCJ16(C)AQ	16.0	17.80	19.7	1.0	5.0	26.0	57.7	BEP	GEP
SMCJ17(C)AQ	17.0	18.90	20.9	1.0	5.0	27.6	53.3	BER	GER
SMCJ18(C)AQ	18.0	20.00	22.1	1.0	5.0	29.2	51.4	BET	GET
SMCJ20(C)AQ	20.0	22.20	24.5	1.0	5.0	32.4	46.3	BEV	GEV
SMCJ22(C)AQ	22.0	24.40	27.0	1.0	5.0	35.5	42.2	BEX	GEX
SMCJ24(C)AQ	24.0	26.70	29.5	1.0	5.0	38.9	38.6	BEZ	GEZ
SMCJ26(C)AQ	26.0	28.90	31.9	1.0	5.0	42.1	35.6	BFE	GFE
SMCJ28(C)AQ	28.0	31.10	34.4	1.0	5.0	45.4	33.0	BFG	GFG
SMCJ30(C)AQ	30.0	33.30	36.8	1.0	5.0	48.4	31.0	BFK	GFK
SMCJ33(C)AQ	33.0	36.70	40.6	1.0	5.0	53.3	28.1	BFM	GFM
SMCJ36(C)AQ	36.0	40.00	44.2	1.0	5.0	58.1	25.8	BFP	GFP
SMCJ48(C)AQ	48.0	53.30	58.9	1.0	5.0	77.4	19.4	BFX	GFX
SMCJ51(C)AQ	51.0	56.70	62.7	1.0	5.0	82.4	18.2	BFZ	GFZ
SMCJ85(C)AQ	85.0	94.40	104	1.0	5.0	137.0	10.4	BGV	GGV

Notes: 8. Suffix C denotes bidirectional device.
9. V_{BR} measured with I_T current pulse = 10ms to 15ms.
10. Per 10 × 1000μs waveform. See Figure 4.
11. For bidirectional devices having V_{RWM} of 10V and under, the I_R is doubled.

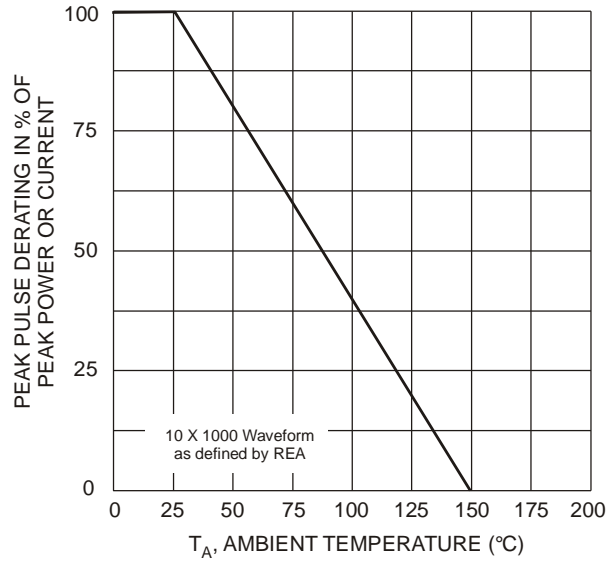


Fig. 1 Pulse Derating Curve

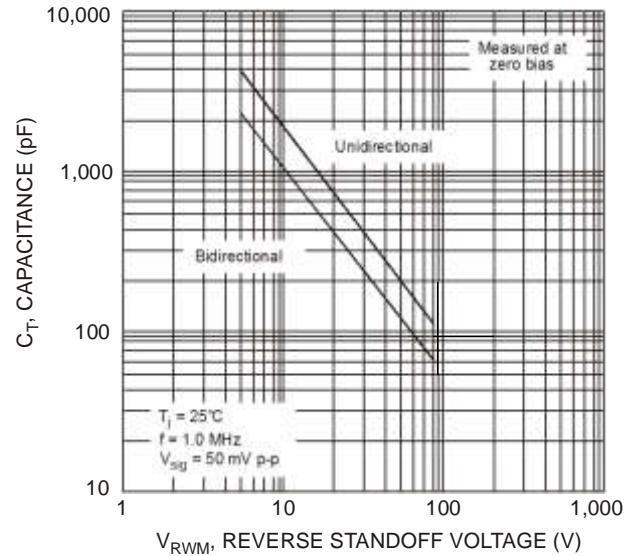


Fig. 2 Typical Total Capacitance

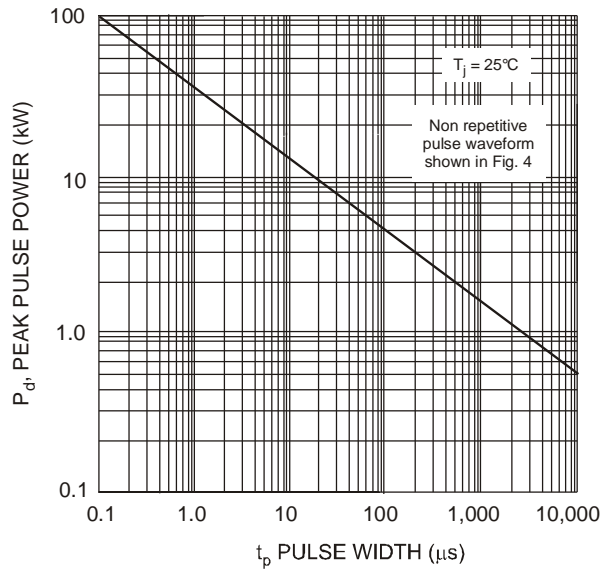


Fig. 3 Pulse Rating Curve

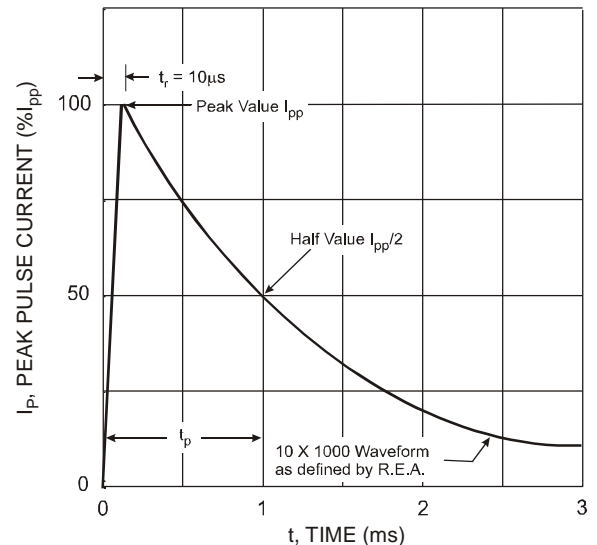


Fig. 4 Pulse Waveform

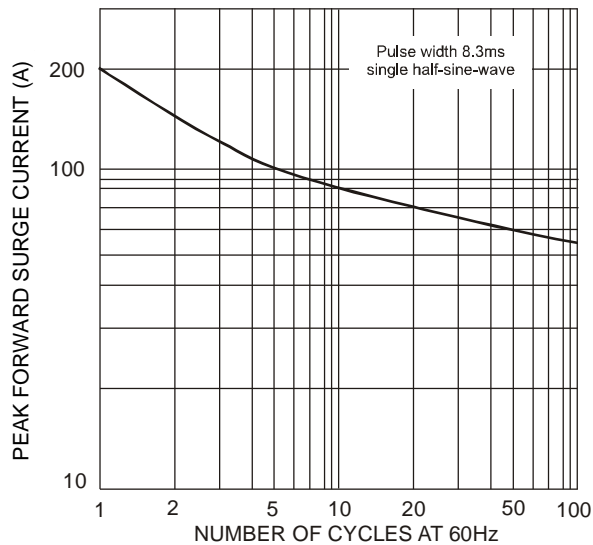


Fig. 5 Maximum Non-Repetitive Surge Current

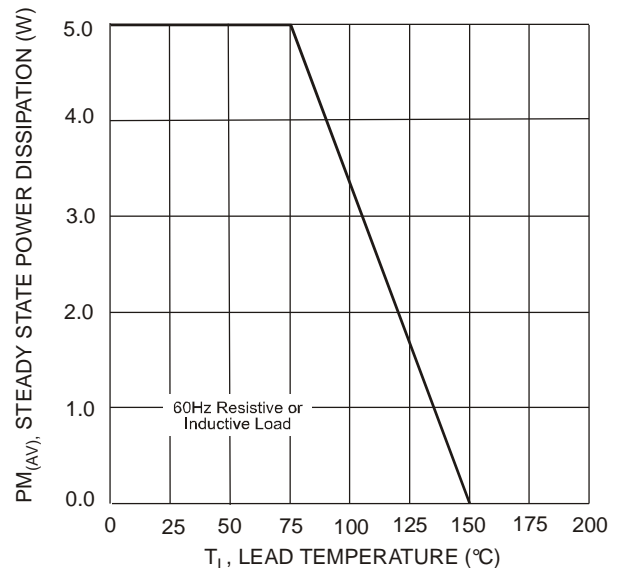
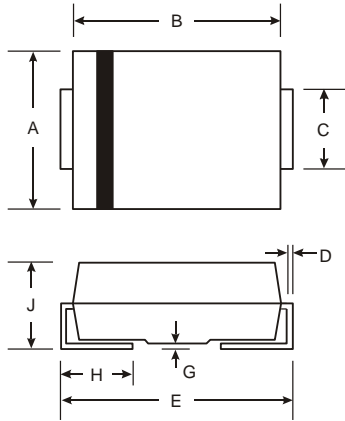


Fig. 6 Steady State Power Derating Curve

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SMC

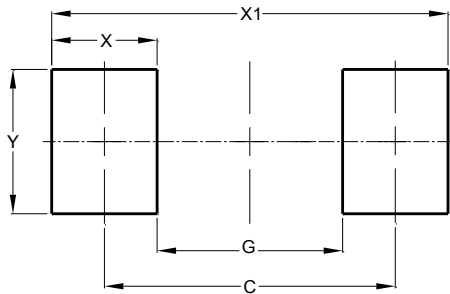


SMC		
Dim	Min	Max
A	5.59	6.22
B	6.60	7.11
C	2.75	3.18
D	0.15	0.31
E	7.75	8.13
G	0.10	0.20
H	0.76	1.52
J	2.00	2.50
All Dimensions in mm		

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SMC



Dimensions	Value (in mm)
C	6.90
G	4.40
X	2.50
X1	9.40
Y	3.30

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